

FEATURES

Single Supply Operation:

- Input Goes Below Ground
- Output Swings to Ground Sinking Current
- No Pull-Down Resistors Needed
- Phase Reversal Protection

At 5V, 0V Low Cost Grade Specifications:

- 280 μ V Max Offset Voltage
- 380 μ V Max in S8 Package
- 0.8nA Max Offset Current
- 480 μ A Max Supply Current per Amplifier
- 0.5 μ V/ $^{\circ}$ C Drift
- 1.4 Million Voltage Gain
- 950kHz Gain-Bandwidth Product
- 0.55 μ V_{P-P}, 0.1Hz to 10Hz Noise

APPLICATIONS

- Single Supply Systems
- Two and Three Op Amp Instrumentation Amplifiers
- Active Filters
- Battery-Powered Systems
- Strain Gauge and Bridge Amplifiers

DESCRIPTION

The LT1413 is a low cost, upgraded version of Linear Technology's industry standard LT1013 dual, single supply op amp. The LT1413 is optimized for single 5V applications, although ± 15 V specifications are also provided for completeness.

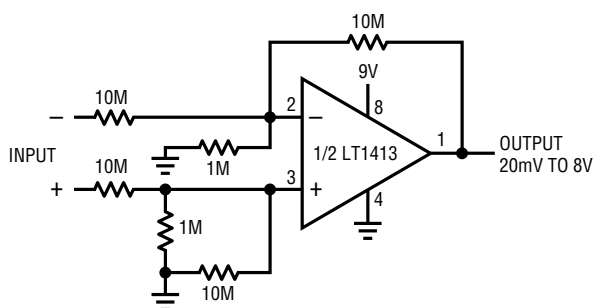
In the design of the LT1413, particular emphasis has been placed on low cost plastic and SO-8 package performance: 60 μ V offset voltage, 0.1nA offset current, in excess of 10mA output current at 330 μ A supply current and 140dB channel separation are some of the specifications achieved.

Other dual, single supply amplifiers are available to complement the LT1413 family: the micropower LT1078's supply current is 10 times lower with a 4.5 fold speed performance degradation compared to the LT1413. Conversely, the LT1211, LT1213 and LT1215 duals have 4 to 14 times higher supply current, but also 13 to 50 times higher speed.

Protected by U.S. Patent 4,775,884.

TYPICAL APPLICATION

**+90V, -3V Common-Mode Range
 Difference Amplifier ($A_V = 1$)**

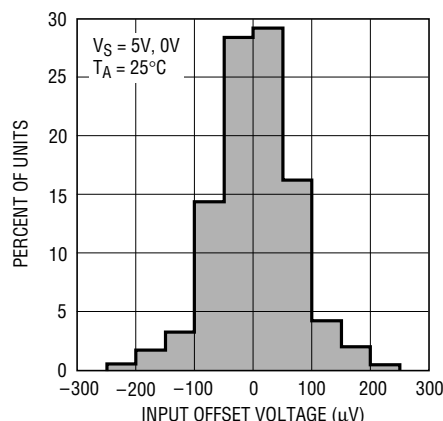


OUTPUT OFFSET = 1.5mV
 (INPUT REFERRED = 125 μ V)
 INPUT RESISTANCE = 11M
 BANDWIDTH = 80kHz

(THE 0.1nA TYPICAL OFFSET CURRENT
 PERMITS THE USE OF 1M Ω RESISTORS)

LT1413 • TA03

**Distribution of Input Offset Voltage
 (In Plastic DIP, N8 Package)**



LT1413 • TA01

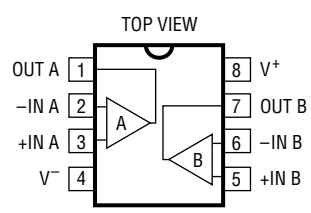
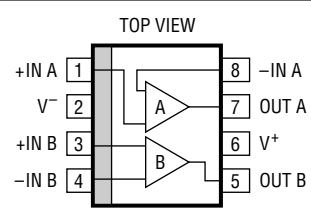
ABSOLUTE MAXIMUM RATINGS

Supply Voltage $\pm 22\text{V}$
 Differential Input Voltage $\pm 30\text{V}$
 Input Voltage
 Equal to Positive Supply Voltage
 5V Below Negative Supply Voltage

Output Short-Circuit Duration Indefinite
 Operating Temperature Range -40°C to 85°C
 Storage Temperature Range -65°C to 150°C
 Lead Temperature (Soldering, 10 sec) 300°C

Note: When the input voltage exceeds the maximum ratings, the input current should be limited to 10mA.

PACKAGE/ORDER INFORMATION

 N8 PACKAGE 8-LEAD PLASTIC DIP $T_{JMAX} = 100^{\circ}\text{C}$, $\theta_{JA} = 130^{\circ}\text{C/W}$	ORDER PART NUMBER	 S8 PACKAGE 8-LEAD PLASTIC SOIC NOTE: THIS PIN CONFIGURATION DIFFERS FROM THE 8-LEAD DIP PIN LOCATIONS. INSTEAD, IT FOLLOWS THE INDUSTRY STANDARD LT1013DS8 SO PACKAGE CONFIGURATION. $T_{JMAX} = 105^{\circ}\text{C}$, $\theta_{JA} = 200^{\circ}\text{C/W}$	ORDER PART NUMBER
	LT1413ACN8 LT1413CN8		LT1413S8
			S8 PART MARKING
			1413

ELECTRICAL CHARACTERISTICS $V_S = 5\text{V}$, 0V , $V_{CM} = 0.1\text{V}$, $V_O = 1.4\text{V}$, $T_A = 25^{\circ}\text{C}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS (Note 1)	LT1413ACN8			LT1413CN8/S8			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage	LT1413N8 LT1413S8		50	150		60 80	280 380	μV μV
$\frac{\Delta V_{OS}}{\Delta \text{Time}}$	Long-Term Input Offset Voltage Stability			0.4			0.5		$\mu\text{V/Mo}$
I_{OS}	Input Offset Current			0.1	0.7		0.1	0.8	nA
I_B	Input Bias Current			9	15		9	18	nA
e_n	Input Noise Voltage	0.1Hz to 10Hz (Note 2)		0.55	1.1		0.55		μV_{P-P}
	Input Noise Voltage Density	$f_0 = 10\text{Hz}$ (Note 2) $f_0 = 1000\text{Hz}$ (Note 2)		24 23	38 30		24 23		$\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$
i_n	Input Noise Current	0.1Hz to 10Hz		2.8			2.8		pA_{P-P}
	Input Noise Current Density	$f_0 = 10\text{Hz}$ $f_0 = 1000\text{Hz}$		0.07 0.02			0.07 0.02		$\text{pA}/\sqrt{\text{Hz}}$ $\text{pA}/\sqrt{\text{Hz}}$
	Input Resistance Differential Mode Common Mode	(Note 3)	300	500 3		250	500 3		$\text{M}\Omega$ $\text{G}\Omega$
	Input Voltage Range		3.65 0	3.8 -0.3		3.65 0	3.8 -0.3		V V
CMRR	Common-Mode Rejection Ratio	$V_{CM} = 0\text{V}$ to 3.65V	90	101		88	101		dB
PSRR	Power Supply Rejection Ratio	$V_S = 3.2\text{V}$ to 12V	102	118		100	118		dB
A_{VOL}	Large-Signal Voltage Gain	$V_O = 0.05\text{V}$ to 4V , No Load $V_O = 0.05\text{V}$ to 3.5V , $R_L = 2\text{k}$	400 300	1400 1000		350 250	1400 1000		V/mV V/mV

ELECTRICAL CHARACTERISTICS $V_S = 5V, 0V, V_{CM} = 0.1V, V_O = 1.4V, T_A = 25^\circ C$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	LT1413ACN8			LT1413CN8/S8			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
	Maximum Output Voltage Swing	Output Low, No Load		15	25		15	25	mV
		Output Low, 600Ω to GND		5	10		5	10	mV
		Output Low, $I_{SINK} = 1mA$		220	350		220	350	mV
		Output High, No Load	4.1	4.4		4.1	4.4		V
		Output High, 600Ω to GND	3.4	4.0		3.4	4.0		V
SR	Slew Rate	$A_V = 1$	0.2	0.3		0.2	0.3		V/μs
GBW	Gain-Bandwidth Product	$f_0 \leq 100kHz$ (Note 4)	600	950		600	950		kHz
I_S	Supply Current per Amplifier			330	450		330	480	μA
	Channel Separation	$\Delta V_{IN} = 3V, R_L = 2k$ (Note 5)	125	140		123	140		dB
	Minimum Supply Voltage	(Note 6)		2.85	3.0		2.85	3.0	V

$V_S = 5V, 0V, V_{CM} = 0.1V, V_O = 1.4V, 0^\circ C \leq T_A \leq 70^\circ C$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS (Note 1)		LT1413ACN8			LT1413CN8/S8			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage	LT1413N8 LT1413S8	● ●		65	240		80 100	390 490	μV μV
$\Delta V_{OS}/\Delta T$	Input Offset Voltage Drift	(Note 5)	●		0.3	2.0		0.4	2.5	μV/°C
I_{OS}	Input Offset Current		●		0.1	1.0		0.1	1.2	nA
I_B	Input Bias Current		●		10	20		10	23	nA
CMRR	Common-Mode Rejection Ratio	$V_{CM} = 0V$ to 3.6V	●	88	100		85	100		dB
PSRR	Power Supply Rejection Ratio	$V_S = 3.45V$ to 12V	●	100	117		97	117		dB
A_{VOL}	Large-Signal Voltage Gain	$V_O = 0.07V$ to 3.9V, No Load $V_O = 0.07V$ to 3.2V, $R_L = 2k$	● ●	300 200	1100 800		300 200	1100 800		V/mV V/mV
	Maximum Output Voltage Swing	Output Low, No Load	●		18	32		18	32	mV
		Output Low, $I_{SINK} = 1mA$	●		270	430		270	430	mV
		Output High, No Load	●	4.0	4.3		4.0	4.3		V
		Output High, 600Ω to GND	●	3.3	3.9		3.2	3.9		V
I_S	Supply Current per Amplifier		●		350	500		350	530	μA

$V_S = 5V, 0V, V_{CM} = 0.1V, V_O = 1.4V, -40^\circ C \leq T_A \leq 85^\circ C$ (Note 7)

SYMBOL	PARAMETER	CONDITIONS (Note 1)		LT1413ACN8			LT1413CN8/S8			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage	LT1413N8 LT1413S8	● ●		70	300		85 110	470 570	μV μV
$\Delta V_{OS}/\Delta T$	Input Offset Voltage Drift		●		0.3	2.2		0.4	2.8	μV/°C
I_{OS}	Input Offset Current		●		0.2	1.4		0.2	1.7	nA
I_B	Input Bias Current		●		11	25		11	30	nA
CMRR	Common-Mode Rejection Ratio	$V_{CM} = 0V$ to 3.4V	●	85	99		82	99		dB
PSRR	Power Supply Rejection Ratio	$V_S = 3.9V$ to 12V	●	98	116		94	116		dB
A_{VOL}	Large-Signal Voltage Gain	$V_O = 0.08V$ to 3.8V, No Load $V_O = 0.08V$ to 3.0V, $R_L = 2k$	● ●	220 150	1000 700		220 150	1000 700		V/mV V/mV
	Maximum Output Voltage Swing	Output Low, No Load	●		20	38		20	38	mV
		Output Low, $I_{SINK} = 1mA$	●		300	480		300	480	mV
		Output High, No Load	●	3.9	4.2		3.9	4.2		V
		Output High, 600Ω to GND	●	3.1	3.8		3.0	3.8		V
I_S	Supply Current per Amplifier		●		360	550		360	580	μA

ELECTRICAL CHARACTERISTICS

$V_S = \pm 15V$, $T_A = 25^\circ C$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS (Note 1)	LT1413ACN8			LT1413CN8/S8			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage	LT1413N8 LT1413S8		75	280		90 110	480 580	μV μV
I_{OS}	Input Offset Current			0.1	0.7		0.1	0.8	nA
I_B	Input Bias Current			8	15		8	18	nA
	Input Voltage Range		13.5 –15.0	13.8 –15.3		13.5 –15.0	13.8 –15.3		V V
CMRR	Common-Mode Rejection Ratio	$V_{CM} = 13.5V, -15V$	100	117		97	114		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2V$ to $\pm 18V$	103	120		100	117		dB
A_{VOL}	Large-Signal Voltage Gain	$V_O = \pm 10V$, $R_L = 2k$	1500	5000		1200	4000		V/mV
V_{OUT}	Maximum Output Voltage Swing	$R_L = 2k$	± 13	± 14		± 12.5	± 14		V
SR	Slew Rate		0.2	0.4		0.2	0.4		V/ μs
I_S	Supply Current per Amplifier			350	500		350	550	μA

$V_S = \pm 15V$, $0^\circ C \leq T_A \leq 70^\circ C$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS (Note 1)		LT1413ACN8			LT1413CN8/S8			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage	LT1413N8 LT1413S8	● ●		95	390		110 130	620 720	μV μV
$\Delta V_{OS}/\Delta T$	Input Offset Voltage Drift	(Note 5)	●		0.4	2.5		0.5	3.0	$\mu V/^\circ C$
I_{OS}	Input Offset Current		●		0.1	1.0		0.1	1.2	nA
I_B	Input Bias Current		●		9	20		9	23	nA
A_{VOL}	Large-Signal Voltage Gain	$V_O = \pm 10V$, $R_L = 2k$	●	1000	4000		700	3000		V/mV
CMRR	Common-Mode Rejection Ratio	$V_{CM} = 13V, -15V$	●	98	116		94	113		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2V$ to $\pm 18V$	●	101	119		97	116		dB
	Maximum Output Voltage Swing	$R_L = 2k$	●	± 12.5	± 13.9		± 12.0	± 13.9		V
I_S	Supply Current per Amplifier		●		360	550		360	600	μA

$V_S = \pm 15V$, $-40^\circ C \leq T_A \leq 85^\circ C$ (Note 7)

SYMBOL	PARAMETER	CONDITIONS (Note 1)		LT1413ACN8			LT1413CN8/S8			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage	LT1413N8 LT1413S8	● ●		100	460		120 140	700 800	μV μV
$\Delta V_{OS}/\Delta T$	Input Offset Voltage Drift		●		0.4	2.8		0.5	3.3	$\mu V/^\circ C$
I_{OS}	Input Offset Current		●		0.2	1.4		0.2	1.7	nA
I_B	Input Bias Current		●		10	25		10	30	nA
A_{VOL}	Large-Signal Voltage Gain	$V_O = \pm 10V$, $R_L = 2k$	●	800	3000		500	2400		V/mV
CMRR	Common-Mode Rejection Ratio	$V_{CM} = 13V, -15V$	●	97	115		92	112		dB
PSRR	Power Supply Rejection Ratio	$V_S \pm 2V$ to $\pm 18V$	●	100	118		95	115		dB
	Maximum Output Voltage Swing	$R_L = 2k$	●	± 12.2	± 13.8		± 11.8	± 13.8		V
I_S	Supply Current per Amplifier		●		370	580		370	630	μA

The ● denotes specifications which apply over the full operating temperature range.

Note 1: Typical parameters are defined as the 60% yield of parameter distributions of individual amplifiers; i.e., out of 100 LT1413s typically 120 op amps will be better than the indicated specification.

Note 2: This parameter is tested on a sample basis only. All noise parameters are tested with $V_S = \pm 2.5V$, $V_O = 0V$.

Note 3: This parameter is guaranteed by design and is not tested.

Note 4: Gain-Bandwidth Product is not tested. It is inferred from the slew rate measurement.

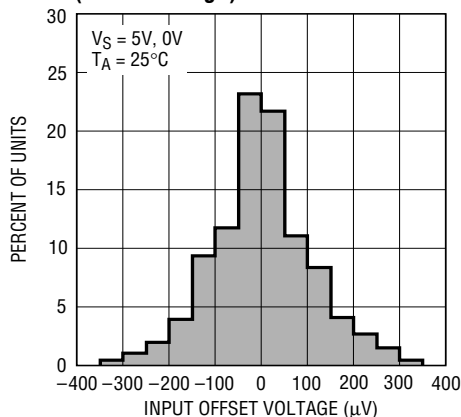
Note 5: This parameter is not 100% tested.

Note 6: At the minimum supply voltage, the offset voltage changes less than 200 μV compared to its value at 5V, 0V.

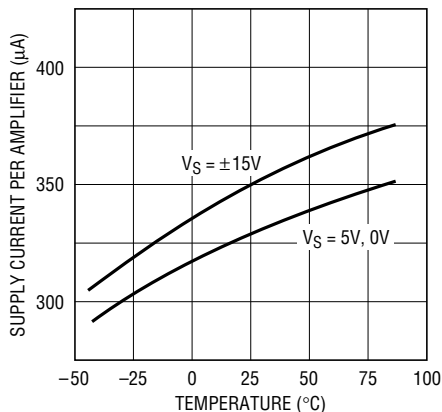
Note 7: The LT1413 is not tested and is not quality-assurance sampled at $-40^\circ C$ and at $85^\circ C$. These specifications are guaranteed by design, correlation and/or inference from $0^\circ C$, $25^\circ C$ and/or $70^\circ C$ tests.

TYPICAL PERFORMANCE CHARACTERISTICS

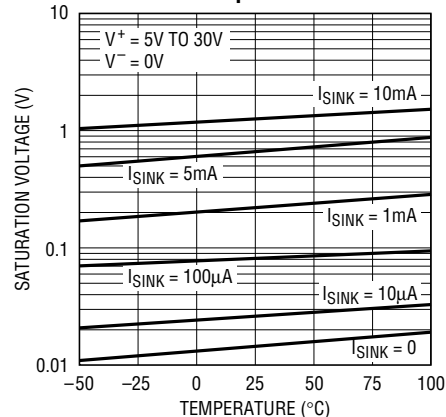
**Distribution of Input Offset Voltage
(In S8 Package)**



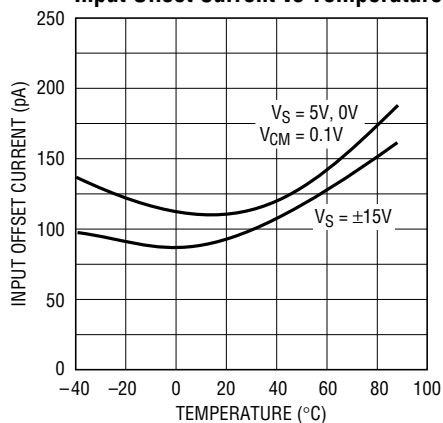
Supply Current vs Temperature



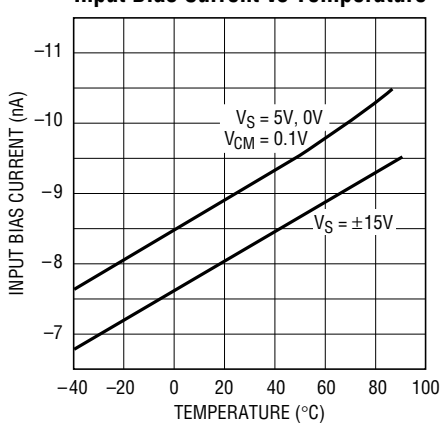
**Output Saturation vs Sink
Current vs Temperature**



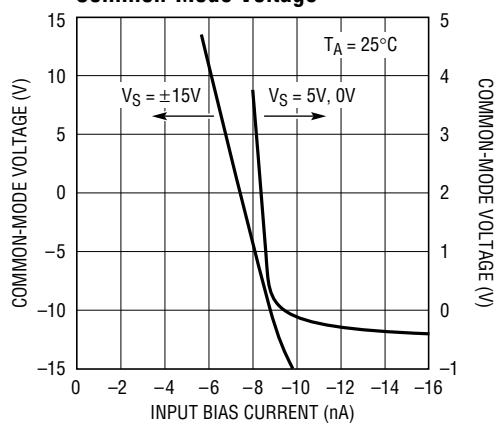
Input Offset Current vs Temperature



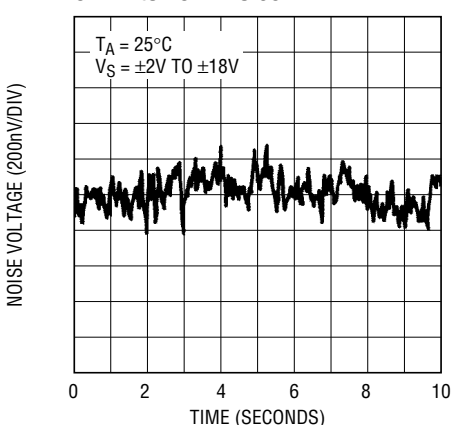
Input Bias Current vs Temperature



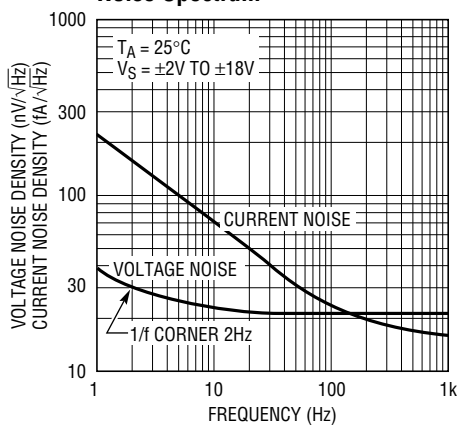
**Input Bias Current vs
Common-Mode Voltage**



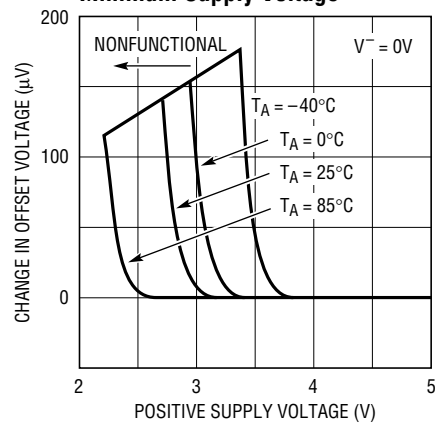
0.1Hz to 10Hz Noise



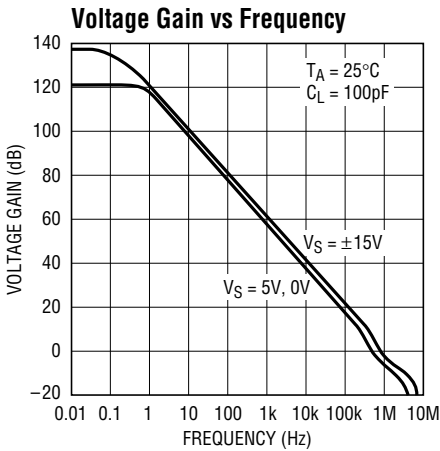
Noise Spectrum



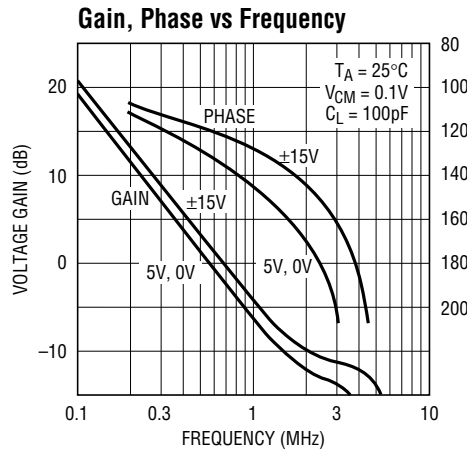
Minimum Supply Voltage



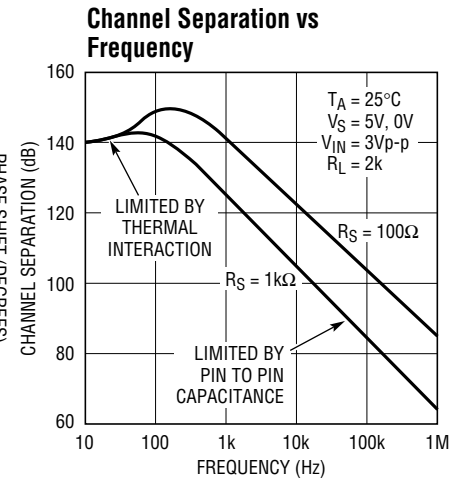
TYPICAL PERFORMANCE CHARACTERISTICS



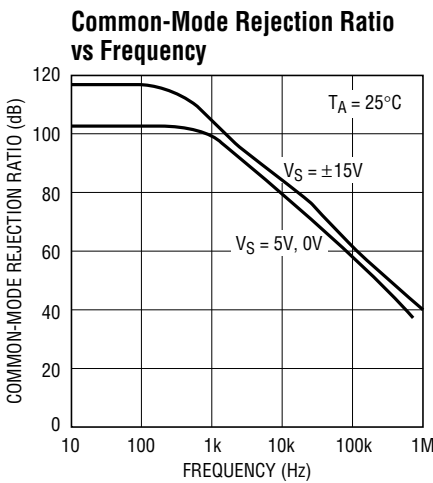
LT1413 • TA12



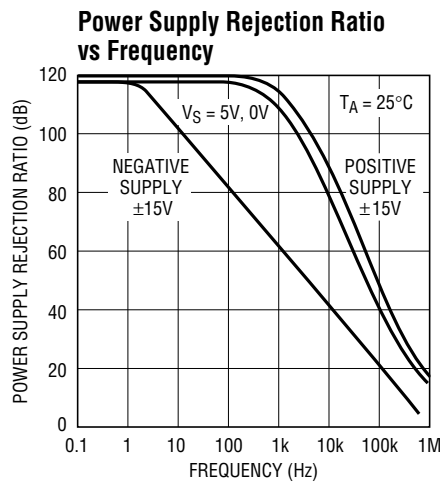
LT1413 • TA13



LT1413 • TA14

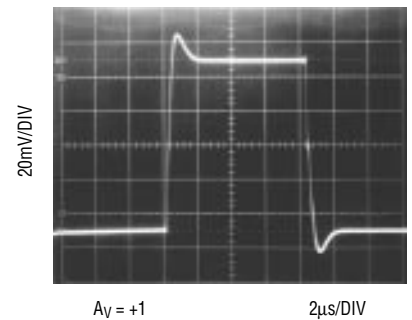


LT1413 • TA15



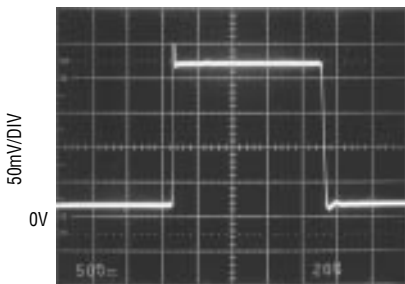
LT1413 • TA16

Small Signal Transient Response, VS = ±15V



LT1413 • TA17

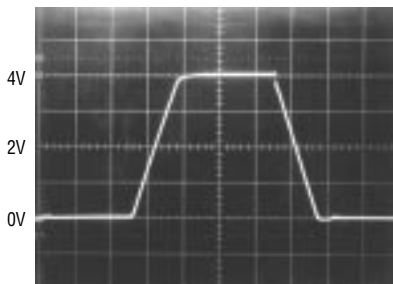
Small Signal Transient Response, VS = 5V, 0V



AV = +1
INPUT = 20mV TO 220mV PULSE

LT1413 • TA18

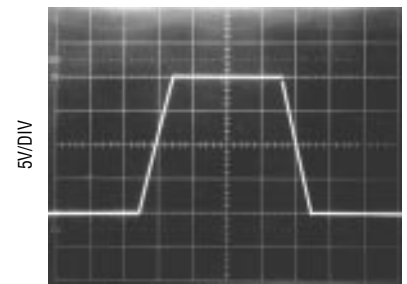
Large Signal Transient Response, VS = 5V, 0V



AV = +1
NO LOAD
INPUT = 0V TO 4V PULSE

LT1413 • TA19

Large Signal Transient Response, VS = ±15V



AV = +1

LT1413 • TA20

APPLICATIONS INFORMATION

Single Supply Operation

The LT1413 is fully specified for single supply operation, i.e., when the negative supply is 0V. Input common-mode range includes ground; the output swings within a few millivolts of ground.

If the input is more than a few hundred millivolts below ground, two distinct problems can occur on previous single supply designs, such as the LM124, LM158, OP-21 and OP-221.

a) When the input is more than a diode drop below ground, unlimited current will flow from the substrate (V^- terminal) to the input. This can destroy the unit. On the LT1413, the 400 Ω resistors, in series with the input (see Schematic Diagram), protect the devices even when the input is 5V below ground.

b) When the input is more than 400mV below ground (at 25°C), the input stage saturates (transistors Q3 and Q4) and phase reversal occurs at the output. This can cause lock-up in servo systems. Due to a unique phase reversal protection circuitry (Q21, Q22, Q27, Q28), the LT1413 outputs do not reverse, as illustrated below, even when the inputs are at -1.5V. Keep the output of the

other amplifier out of negative saturation for the phase reversal protection to function properly.

Since the output of the LT1413 cannot go exactly to ground, but can only approach ground to within a few millivolts, care should be exercised to ensure that the output is not saturated. For example, a 1mV input signal will cause the amplifier to set up in its linear region in the gain 100 configuration shown below, but is not enough to make the amplifier function properly in the voltage-follower mode.

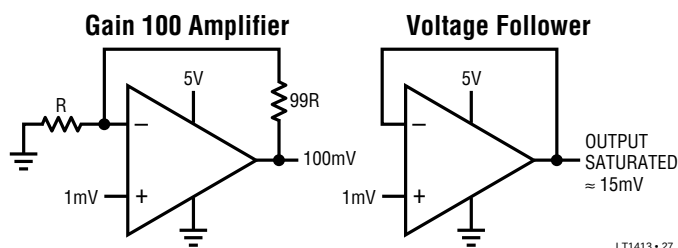


Figure 1.

Comparator Applications

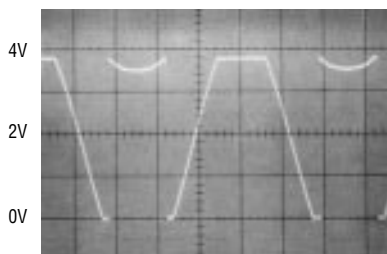
The single supply operation of the LT1413 lends itself to its use as a precision comparator with TTL compatible output; the response time is shown below.

Voltage Follower with Input Exceeding the Negative Common-Mode Range

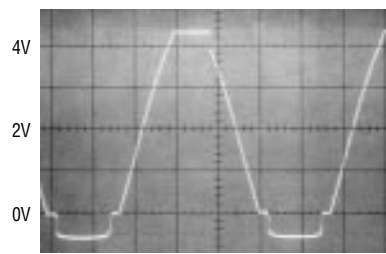


6Vp-p INPUT, -1.5V TO 4.5V

LT1413 • TA21



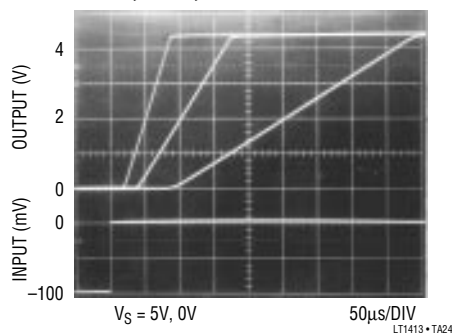
LM324, LM358, OP-221
EXHIBIT OUTPUT PHASE REVERSAL



LT1413
NO PHASE REVERSAL

LT1413 • TA23

Comparator Rise Response Time 10mV, 5mV, 2mV Overdrives

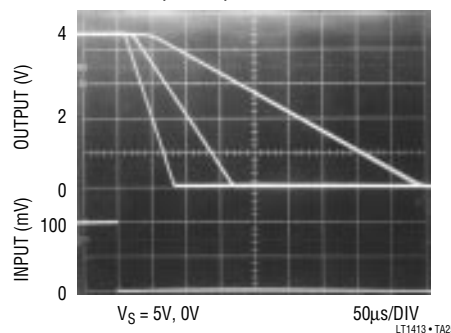


$V_S = 5V, 0V$

50 μ s/DIV

LT1413 • TA24

Comparator Fall Response Time to 10mV, 5mV, 2mV Overdrives

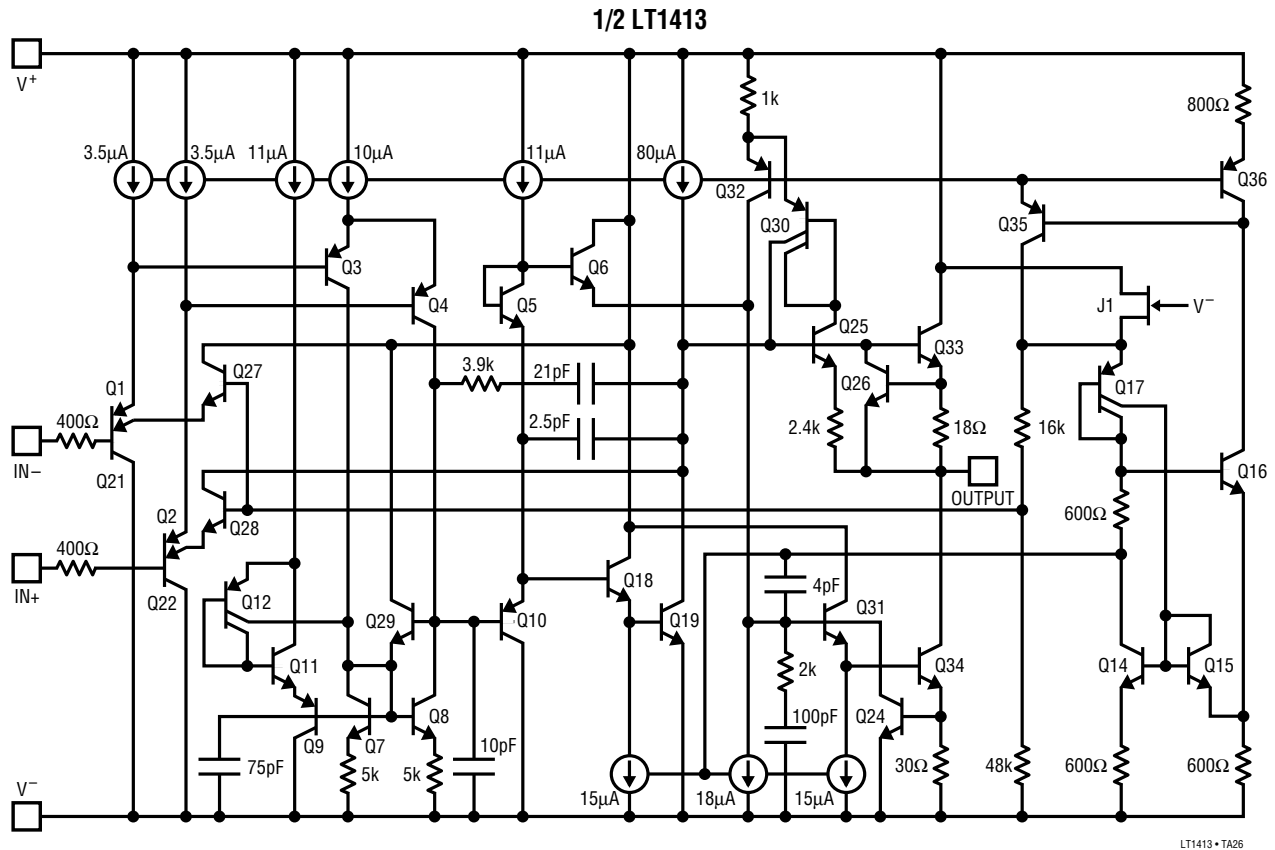


$V_S = 5V, 0V$

50 μ s/DIV

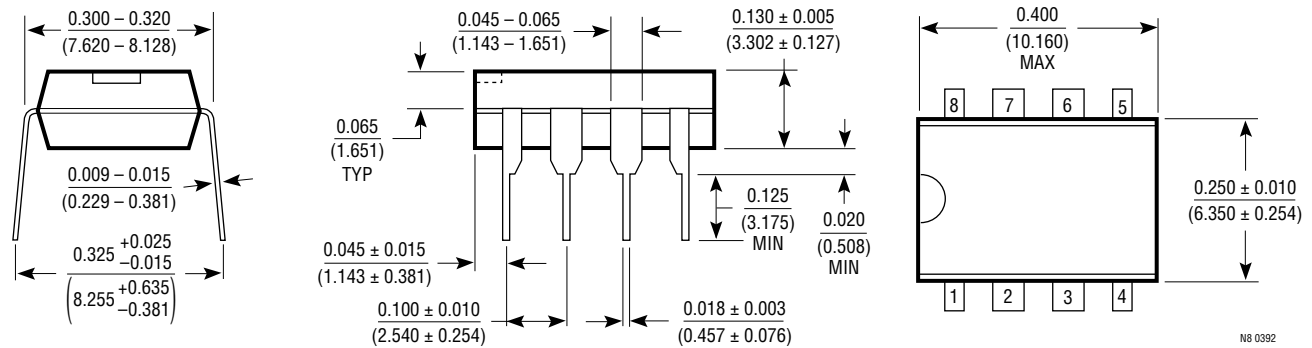
LT1413 • TA25

SIMPLIFIED SCHEMATIC

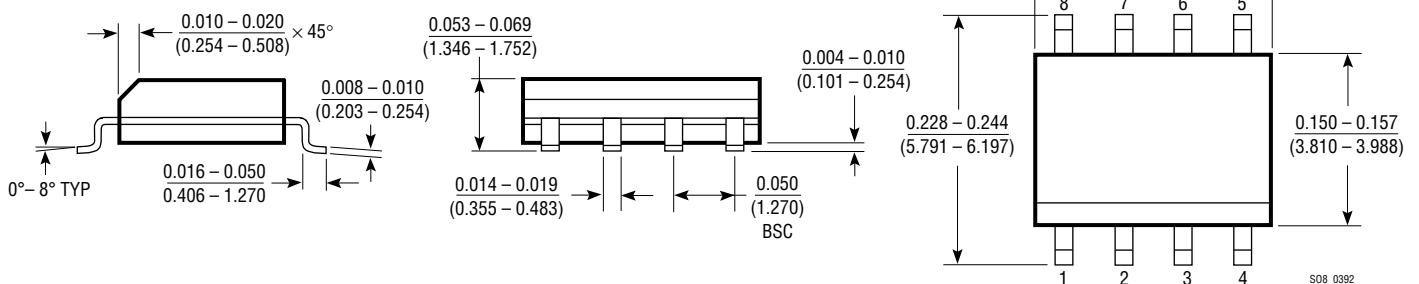


PACKAGE DESCRIPTION

N8 Package, 8-Lead Plastic DIP



S8 Package, 8-Lead Plastic SOIC



Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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